

Single Ultra-High speed and Wide Band Operational Amplifier

■ GENERAL DESCRIPTION

The **NJM2722** is a single, ultra-high speed and wide band operational amplifier that features 1000V/ μ s slew rate and 150ohm load drive, at supply voltage of ± 4.5 V.

The NJM2722 is suitable for video signal processing, video buffer, pulse amplifiers, ADC input buffer, measuring instrument, and digital communication.

■ PACKAGE OUTLINE

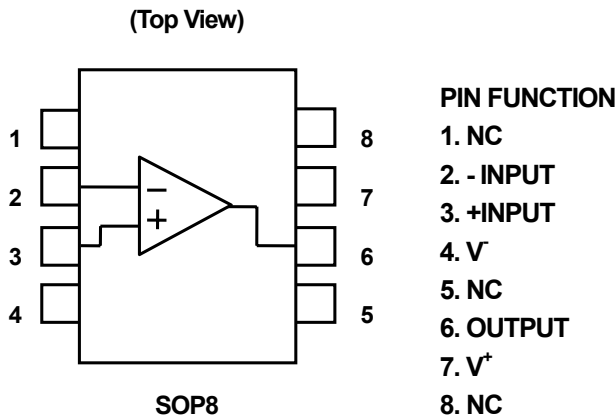


NJM2722E
(SOP8)

■ FEATURES

- Operating Voltage : ± 2.5 V to ± 5.0 V
- Slew Rate : 1000V/ μ s Typ. (at $V^+/V^- = \pm 4.5$ V, $R_L = 1$ k Ω)
- Unity-Gain : 170MHz Typ.
- Output Voltage : $V_{OH} = +3.2$ V Typ. (at $V^+/V^- = \pm 4.5$ V, $R_L = 1$ k Ω)
: $V_{OL} = -3.2$ V Typ. (at $V^+/V^- = \pm 4.5$ V, $R_L = 1$ k Ω)
- Offset Voltage : 5mV Typ.
- Operating Current : 16.5 mA Typ.
- Adequate phase margin : $\Phi_M = 70$ deg. Typ. (at $R_L = 2$ k Ω , voltage follower)
- Bipolar Technology
- Package Outline : SOP8 JEDEC 150mil

■ PIN CONFIGURATION



NJM2722

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V^+ / V^-	±5.5	V
Power Dissipation	P_D	SOP8: 730 (Note1)	mW
Differential Input Voltage Range	V_{ID}	±3.0	V
Common Mode Input Voltage Range	V_{ICM}	±5.5 (Note2)	V
Operating Temperature Range	T_{opr}	-40 to +85	°C
Storage Temperature Range	T_{stg}	-40 to +150	°C

(Note 1) On the PCB " EIA/JEDEC (76.2x11.43x1.6mm, four layers, FR-4) "

(Note 2) For supply voltage less than ±5.5V, the absolute maximum input voltage is equal to the supply voltage.

■ RECOMMENDED OPERATING CONDITION

(Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V^+ / V^-	±2.5 to ±5.0	V

■ ELECTRICAL CHARACTERISTICS

● DC CHARACTERISTICS

($V^+ / V^- = \pm 2.5V$, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Current	I_{CC}	No Signal	-	16.5	25.5	mA
Input Offset Voltage	V_{IO}		-	5.0	28.0	mV
Input Bias Current	I_B		-	25.5	70.0	μA
Input Offset Current	I_{IO}		-	0.3	1.7	μA
Large Signal Voltage Gain	A_V	$R_L = 2k\Omega$ (Note 3)	50	60	-	dB
Input Common Mode Voltage Range	V_{ICM}	$V^+ / V^- = \pm 4.5V$	+3.1	+3.5	-	V
			-2.7	-3.0	-	V
Common Mode Rejection Ratio	CMR	$V^+ / V^- = \pm 4.5V$ $-2.7V \leq V_{ICM} \leq +3.1V$	60	80	-	dB
Supply Voltage Rejection Ratio	SVR	$\pm 2.5V \leq V^+ / V^- \leq \pm 5.0V$	50	60	-	dB
Maximum Output Voltage Swing	V_{OM}	$V^+ / V^- = \pm 4.5V$, $R_L = 1k\Omega$	±2.9	±3.2	-	V

(Note 3) When using NJM2722, the closed gain should be 40dB or lower.

● AC CHARACTERISTICS

($V^+ / V^- = \pm 4.5V$, Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Unity Gain Frequency	f_T	$A_V = 40dB$, $R_F = 1.98k\Omega$ $R_G = 20\Omega$, $R_L = \infty$, $C_L = 5pF$	-	170	-	MHz
Phase Margin	Φ_M	$A_V = 40dB$, $R_F = 1.98k\Omega$ $R_G = 20\Omega$, $R_L = \infty$, $C_L = 5pF$	-	70.0	-	Deg

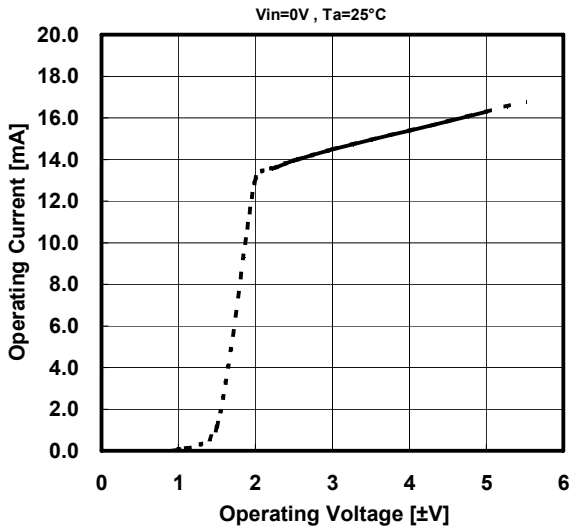
● AC CHARACTERISTICS

($V^+ / V^- = \pm 4.5V$, Ta=25°C)

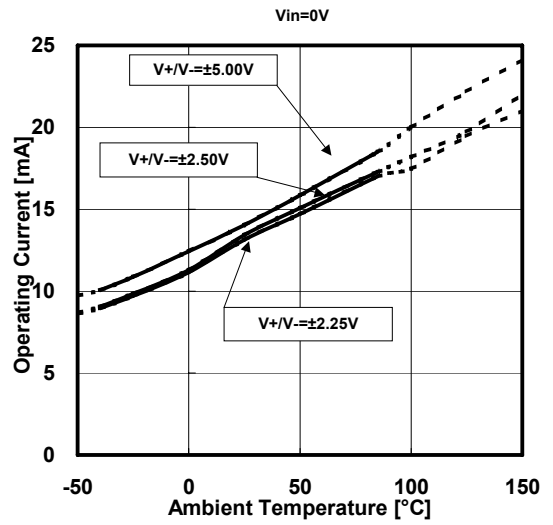
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Slew Rate	SR	$A_V = 0dB$, $R_F = 0\Omega$, $R_G = \infty$ $R_L = 1k\Omega$, $C_L = 1.5pF$ $V_{IN} = 4V_{PP}$	-	1000	-	V/μs

■ TYPICAL CHARACTERISTICS

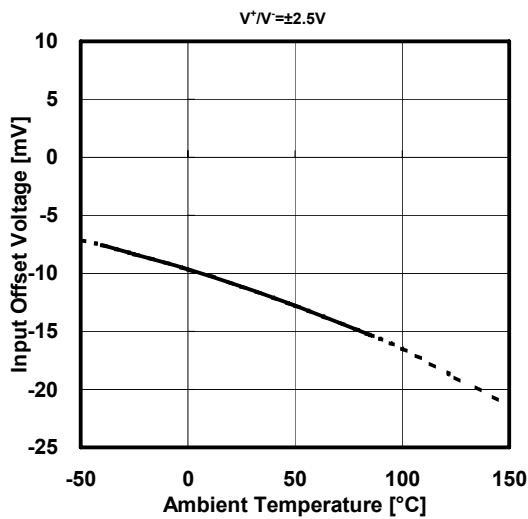
Maximum Output Voltage Swing
vs. Operating Voltage



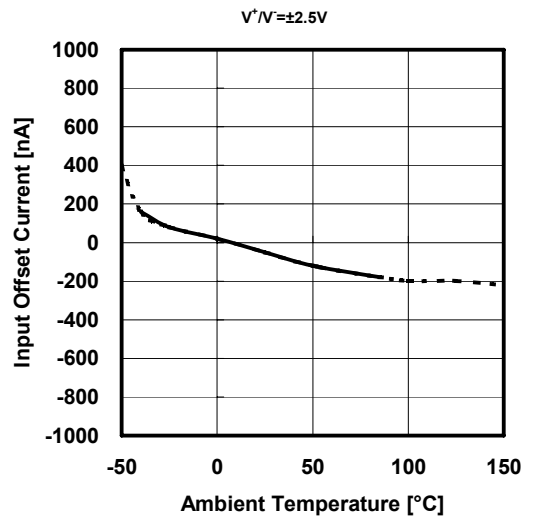
Operating Current vs. Ambient Temperature



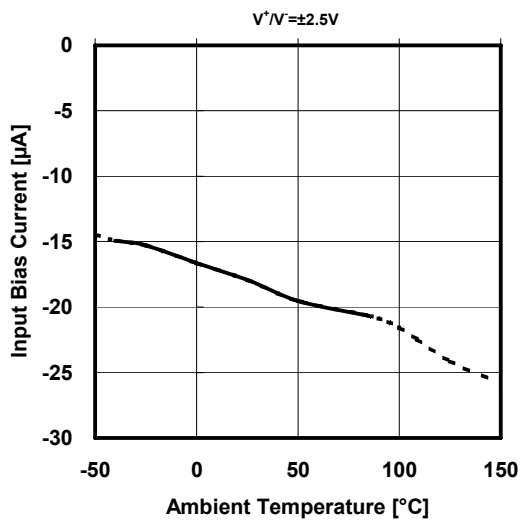
Input Offset Voltage vs. Ambient Temperature



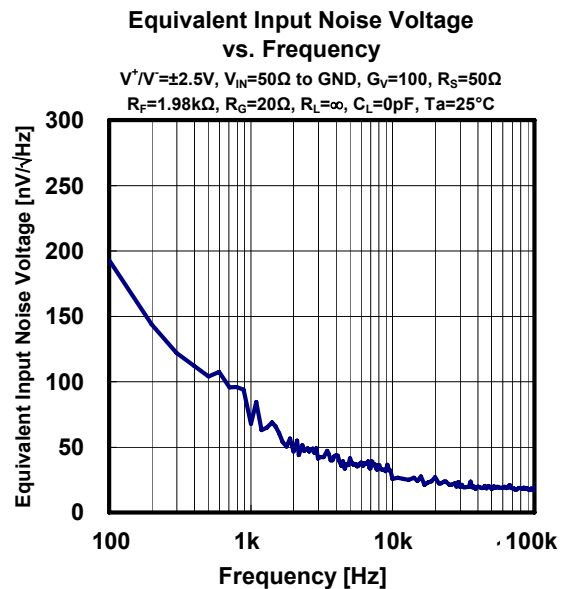
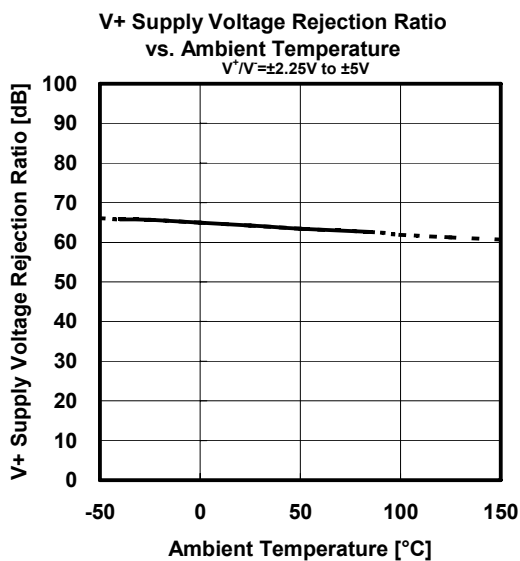
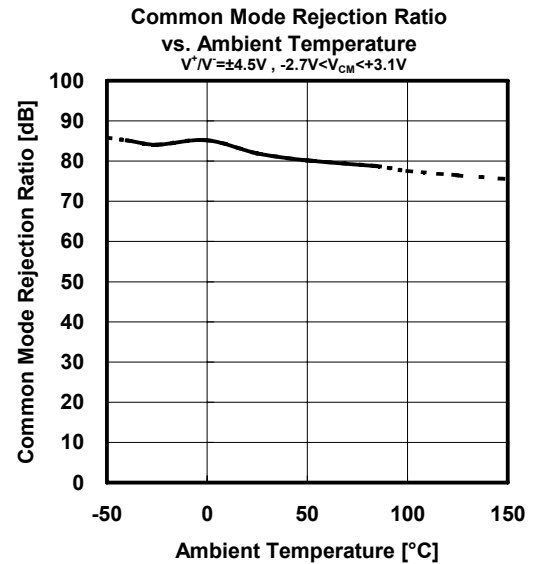
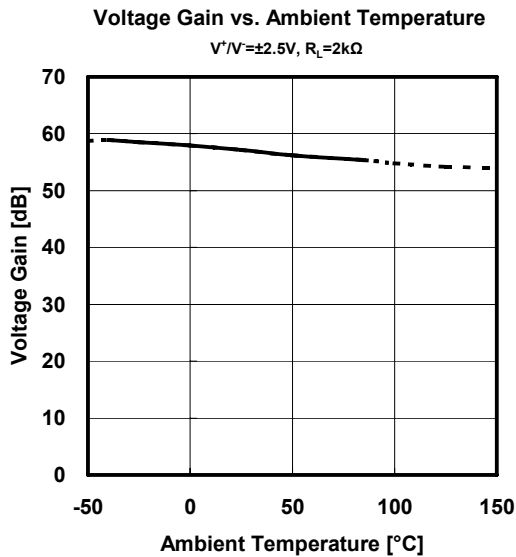
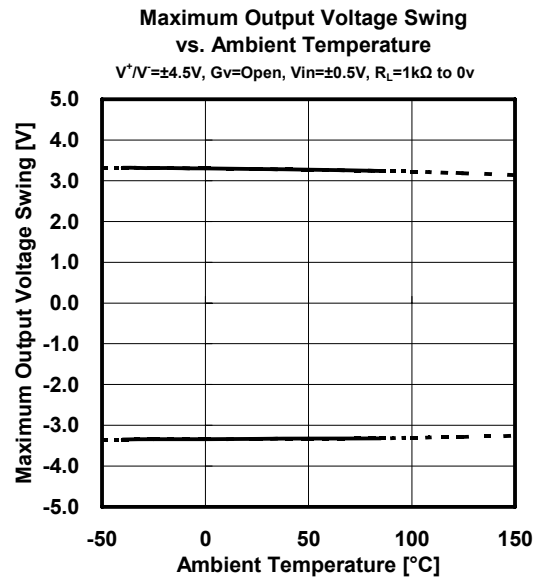
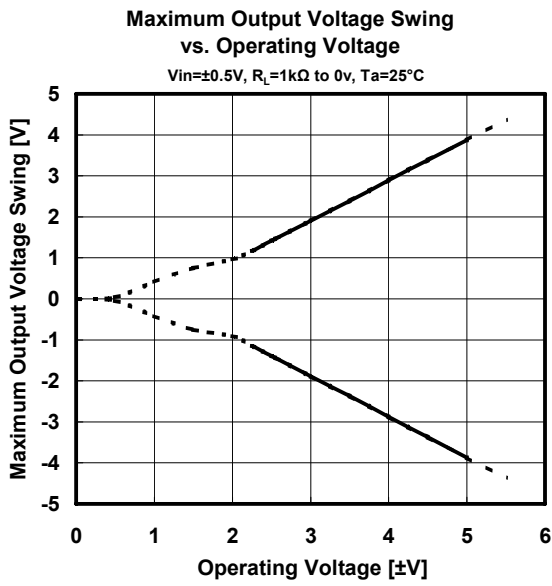
Input Offset Current vs. Ambient Temperature



Input Bias Current vs. Ambient Temperature



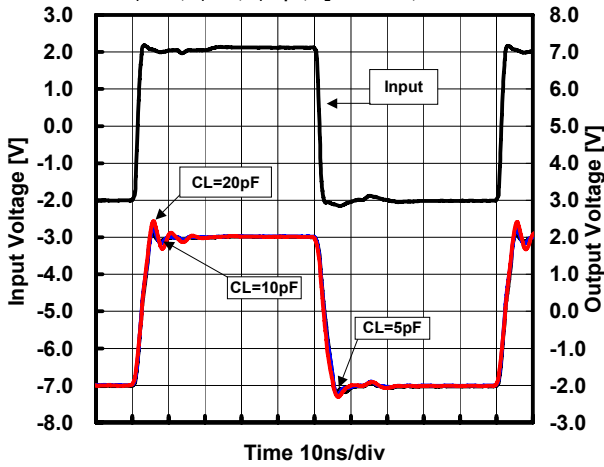
■ TYPICAL CHARACTERISTICS



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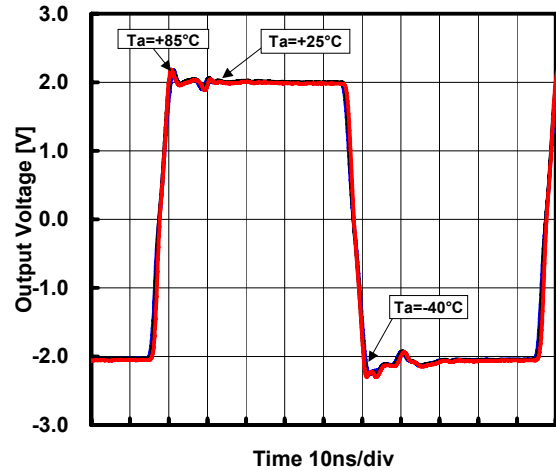
Pulse Response (with Capacitive load)

$V^+ / V^- = \pm 4.5V$, $f = 10MHz$, $V_O = 4V_{pp}$, $G_V = 0dB$
 $R_T = 50\Omega$, $R_F = 0\Omega$, $C_F = 0pF$, $R_L = 1k\Omega$ to 0v, $T_a = +25^\circ C$



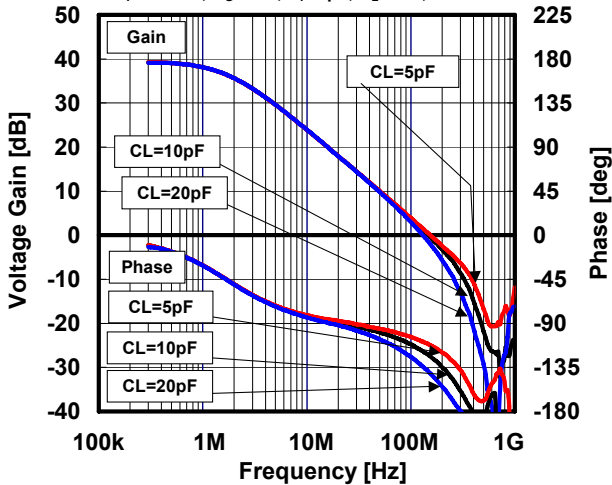
Pulse Response (correlation with T_a)

$V^+ / V^- = \pm 4.5V$, $f = 10MHz$, $V_O = 4V_{pp}$, $G_V = 0dB$
 $R_T = 50\Omega$, $R_F = 0\Omega$, $C_F = 0pF$, $C_L = 5pF$, $R_L = 1k\Omega$ to 0v



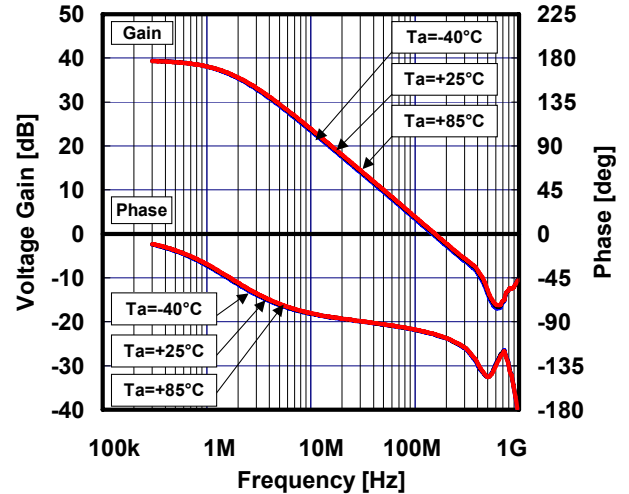
Voltage Gain vs. Frequency (with Capacitive load)

$V^+ / V^- = \pm 4.5V$, $V_{IN} = 0.02V_{pp}$, $G_V = 40dB$, $R_T = 50\Omega$
 $R_F = 1.98k\Omega$, $R_G = 20\Omega$, $C_F = 0pF$, $R_L = 1k\Omega$, $T_a = +25^\circ C$



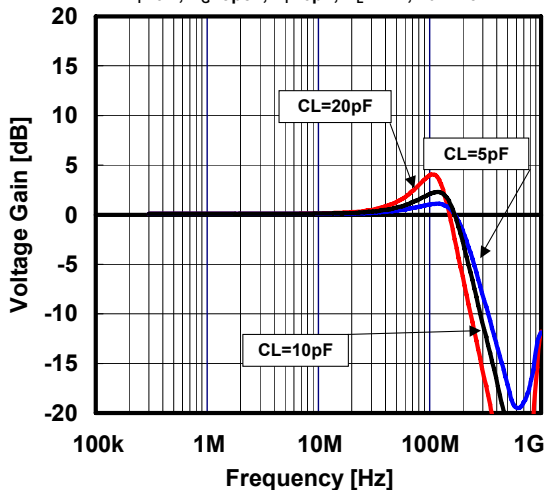
Voltage Gain vs. Frequency (correlation with T_a)

$V^+ / V^- = \pm 2.5V$, $V_{IN} = 0.02V_{pp}$, $G_V = 40dB$, $R_T = 50\Omega$
 $R_F = 1.98k\Omega$, $R_G = 20\Omega$, $C_F = 0pF$, $R_L = 2k\Omega$, $C_L = 5pF$



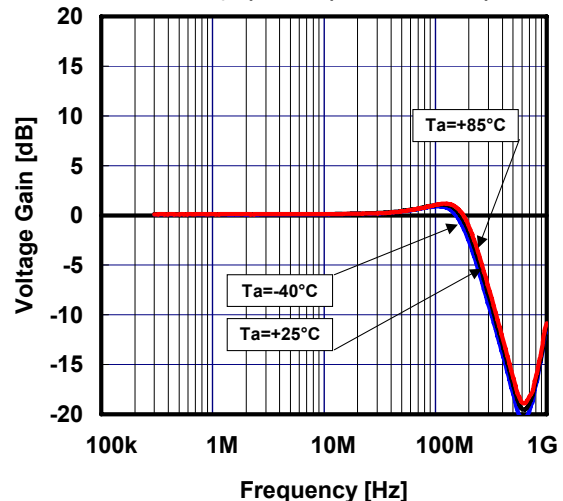
Voltage Gain vs. Frequency (with Capacitive load)

$V^+ / V^- = \pm 4.5V$, $V_{IN} = 0.02V_{pp}$, $G_V = 0dB$, $R_T = 50\Omega$
 $R_F = 0\Omega$, $R_G = \text{open}$, $C_F = 0pF$, $R_L = 1k\Omega$, $T_a = +25^\circ C$



Voltage Gain vs. Frequency (correlation with T_a)

$V^+ / V^- = \pm 4.5V$, $V_{IN} = 0.02V_{pp}$, $G_V = 0dB$, $R_T = 50\Omega$
 $R_F = 0\Omega$, $R_G = \text{open}$, $C_F = 0pF$, $R_L = 1k\Omega$, $C_L = 20pF$



[CAUTION]
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